

2SK2800-VB Datasheet N-Channel 60-V (D-S) MOSFET

PRODUCT	SUMMARY	
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^a
60	0.011 at V _{GS} = 10 V	60
00	0.013 at V _{GS} = 4.5 V	50

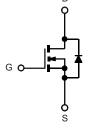
FEATURES

- 175 °C Junction Temperature
- TrenchFET[®] Power MOSFET
- Material categorization:

D







N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25	°C, unless otherw	vise noted)		
Parameter		Symbol	Limit	Unit
Gate-Source Voltage		V _{GS}	± 20	V
	T _C = 25 °C	1_	60	
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 100 °C	I _D	50ª	
Pulsed Drain Current	·	I _{DM}	200	A
Continuous Source Current (Diode Conduction)		I _S	50ª	
Avalanche Current		I _{AS}	50	
Single Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	125	mJ
Maximum Power Dissipation	T _C = 25 °C	P _D	136	W
	T _A = 25 °C		3 ^b , 8.3 ^{b, c}	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mandana lumatian ta Analdanata	t ≤ 10 sec	R _{thJA}	15	18		
Maximum Junction-to-Ambient ^a	Steady State	' ' thJA	40	50	°C/W	
Maximum Junction-to-Case	-	R _{thJC}	0.85	1.1		

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. $t \leq 10$ s.

unless oth	erwise noted)					
Symbol Test Conditions Min.		Min.	Min. Typ.ª		Unit	
			•	· I		
V _{DS}	V_{GS} = 0 V, I _D = 250 µA	60			V	
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	1		3	v	
I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
	V _{DS} = 60 V, V _{GS} = 0 V			1		
I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V, T _J = 125 °C			50	μA	
	V _{DS} = 60 V, V _{GS} = 0 V, T _J = 175 °C			250		
I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	60			А	
	V _{GS} = 10 V, I _D = 20 A		0.011		0	
D	V_{GS} = 10 V, I _D = 20 A, T _J = 125 °C		0.014			
DS(on)	V _{GS} = 10 V, I _D = 20 A, T _J = 175 °C		0.018		Ω	
	V _{GS} = 4.5 V, I _D = 15 A	0.013				
9 _{fs}	V _{DS} = 15 V, I _D = 20 A		60		S	
-			-	· ·		
C _{iss}			4200			
C _{oss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		570		pF	
C _{rss}			325			
Qg			47			
Q _{gs}	V _{DS} = 30 V, V _{GS} = 10 V, I _D = 50 A		10		nC	
Q _{gd}			12			
t _{d(on)}			10	20		
t _r	V_{DD} = 30 V, R _L = 0.6 Ω		15	25	ns	
t _{d(off)}	$I_D{\cong}50$ A, V_{GEN} = 10 V, R_g = 2.5 Ω		35	50		
t _f			20	30		
aracteristics (T _C = 25 °C)					
I _{SM}				60	А	
V _{SD}	$I_{F} = 20 \text{ A}, V_{GS} = 0 \text{ V}$		1	1.5	V	
t _{rr}	I _F = 20 A, di/dt = 100 A/µs		45	100	ns	
	Symbol V _{DS} V _{GS} (th) I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)} gfs C _{iss} C _{oss} C _{rss} Qg Qgd t _{d(on)} t _f t _{d(off)} t _f aracteristics (I _{SM} V _{SD}	$\begin{tabular}{ c c c c } \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A \\ \hline V_{GS}(th) & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 175 \ ^{\circ}C \\ \hline V_{DS} = 10 \ V, \ I_D = 20 \ A \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 4.5 \ V, \ I_D = 15 \ A \\ \hline g_{fs} & V_{DS} = 15 \ V, \ I_D = 20 \ A \\ \hline \hline U_{C} = 0 \ V, \ V_{DS} = 25 \ V, \ f = 1 \ MHz \\ \hline \hline C_{rss} & V_{GS} = 0 \ V, \ V_{DS} = 25 \ V, \ f = 1 \ MHz \\ \hline \hline C_{ns} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline \hline Q_{gd} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline \hline Q_{gd} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline \hline I_D \cong 50 \ A, \ V_{GEN} = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline I_D \cong 50 \ A, \ V_{GEN} = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline \hline I_{SM} & I_F = 20 \ A, \ V_{GS} = 0 \ V \\ \hline \hline \end{tabular}$	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions & Min. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 1 \\ \hline I_{GSS} & V_{DS} = V_{CS}, \ I_D = 250 \ \mu A & 1 \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 10 \ V, \ I_D = 20 \ A \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 4.5 \ V, \ I_D = 15 \ A \\ \hline g_{fs} & V_{DS} = 15 \ V, \ I_D = 20 \ A \\ \hline \hline C_{1SS} \\ \hline Q_{g} \\ \hline t_{d(on)} \\ t_{r} \\ \hline V_{DD} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline e_{1D} = 50 \ A, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline e_{1D} = 50 \ A, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline e_{1D} = 50 \ A, \ V_{GS} = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline I_F = 20 \ A, \ V_{GS} = 0 \ V \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions & Min. Typ.^a \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 1 \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & 1 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C & 1 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 175 \ ^{\circ}C & 0.011 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A & 0.011 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.014 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 175 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 15 \ V, \ I_D = 15 \ A & 0.013 \\ \hline g_{fs} & V_{DS} = 30 \ V, \ V_{DS} = 25 \ V, \ f = 1 \ MHz & 570 \\ \hline C_{rss} & 325 \\ \hline Q_g & & 477 \\ \hline Q_{gs} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A & 10 \\ \hline Q_{gd} & 12 \\ \hline t_{d(on)} & t_r & V_{DD} = 30 \ V, \ R_L = 0.6 \ \Omega \\ \hline I_L & V_{GD} = 30 \ V, \ R_L = 0.6 \ \Omega \\ \hline t_r & V_{DD} = 30 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_r & 20 \\ \hline raccteristics \ (T_C = 25 \ ^{\circ}C) \\ \hline I_{SM} & I_F = 20 \ A, \ V_{GS} = 0 \ V & 1 \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions & Min. Typ.* & Max. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 1 & 3 \\ \hline V_{GS}(th) & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 1 & 3 \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V & \pm 100 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & 1 & 1 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & 1 & 1 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & T_J = 125 \ ^{\circ}C & 50 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 175 \ ^{\circ}C & 250 \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 10 \ V & 10 & 0.011 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A & T_J = 125 \ ^{\circ}C & 0.014 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A, \ T_J = 125 \ ^{\circ}C & 0.018 \\ \hline V_{GS} = 10 \ V, \ I_D = 20 \ A & 10 \\ \hline V_{GS} = 10 \ V, \ I_D = 50 \ A & 10 \\ \hline Q_{gd} & 477 \\ \hline Q_{gg} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline I_D = 50 \ A, \ V_{GS} = 10 \ V, \ I_D = 50 \ A \\ \hline V_{DD} = 30 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_d(otf) & I_D = 50 \ A, \ V_{GS} = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_f & I_D = 50 \ A, \ V_{GS} = 0 \ V, \ V_{R_g} = 2.5 \ \Omega \\ \hline T_{SD} & I_D = 20 \ A, \ V_{R_g} = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline T_{T} & I_D = 10 \ V, \ R_g = 0 \ V \ V_T = 10 \ V \ V_T = 1$	

Notes:

a. For design aid only; not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

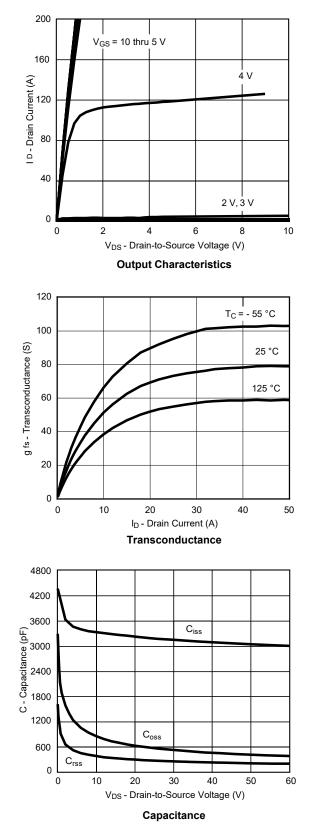
c. Independent of operating temperature.

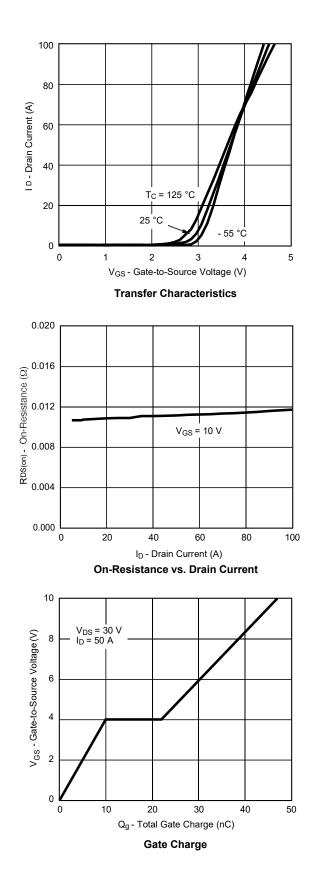
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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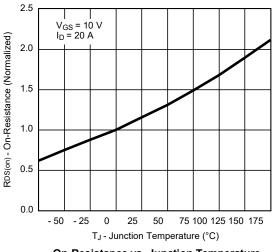
TYPICAL CHARACTERISTICS (25 °C unless noted)



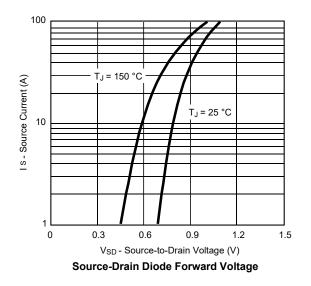




TYPICAL CHARACTERISTICS (25 °C unless noted)

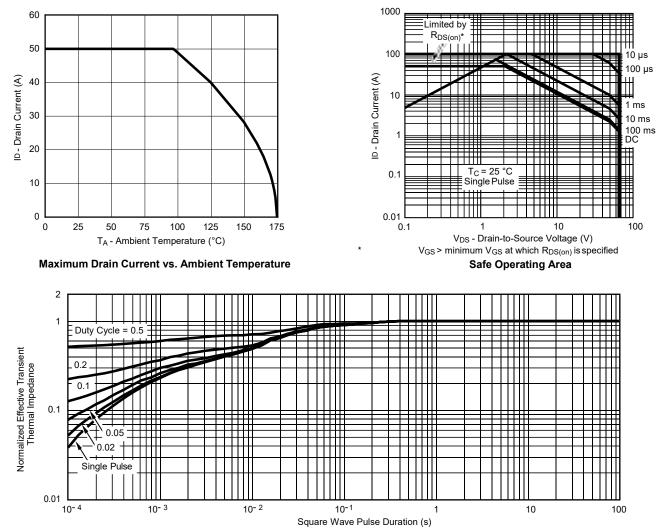


On-Resistance vs. Junction Temperature



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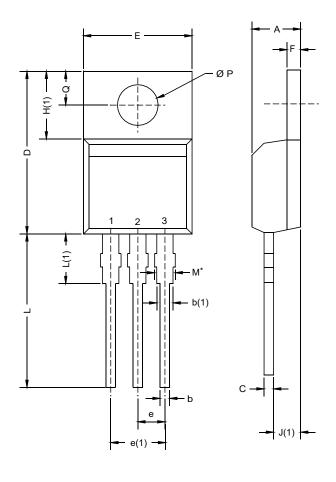
THERMAL RATINGS



Normalized Thermal Transient Impedance, Junction-to-Case



TO-220AB



DIM.	MILLIM	ETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
А	4.24	4.65	0.167	0.183	
b	0.69	1.02	0.027	0.040	
b(1)	1.14	1.78	0.045	0.070	
С	0.36	0.61	0.014	0.024	
D	14.33	15.85	0.564	0.624	
Е	9.96	10.52	0.392	0.414	
е	2.41	2.67	0.095	0.105	
e(1)	4.88	5.28	0.192	0.208	
F	1.14	1.40	0.045	0.055	
H(1)	6.10	6.71	0.240	0.264	
J(1)	2.41	2.92	0.095	0.115	
L	13.36	14.40	0.526	0.567	
L(1)	3.33	4.04	0.131	0.159	
ØР	3.53	3.94	0.139	0.155	
Q	2.54	3.00	0.100	0.118	
ECN: X15- DWG: 603	0364-Rev. C, 1	14-Dec-15			

Note

• M* = 0.052 inches to 0.064 inches (dimension including protrusion), heatsink hole for HVM



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